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## AWT6102M2

EGSM/DCS/PCS Triple Band Power Amplifier Module Advanced Product Information Rev. 2

#### FEATURES

- InGaP HBT Technology
- High Efficiency 55% GSM
- High Efficiency 50% DCS
- High Efficiency 45% PCS
- Low Leakage Current ( <10μA)
- SMT Module Package
- Small Foot Print (9.2mm X 11.6mm)
- Low Profile (1.55 mm)
- 50 Ω Input and Output Matching
- Minimum Number of External Components

#### APPLICATIONS

- GSM/DCS Dual Band Handsets
- GSM/PCS Dual Band Handsets
- GSM/DCS/PCS Triple Band Handsets

# 9x11.6 mm MCM Module Package

AWT6102

#### Description

The AWT6102 is a 3.5V power amplifier module for use in dual Mode GSM/DCS/PCS wireless handsets and communication systems.

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SIGNAL	MIN	MAX	UNITS
Supply Voltage (Vcc)		+7	V
Input Power (RF <sub>N</sub> )		+15	dBm
Control Voltage (V <sub>APC</sub> )		+ 4.3V	V
Storage Temperature (T <sub>STG</sub> )	-55	150	٦°
Operating Temperature (T <sub>c</sub> )	-25	85	°C

#### Absolute Minimum and Maximum Ratings

#### **Electrical Specifications EGSM:**

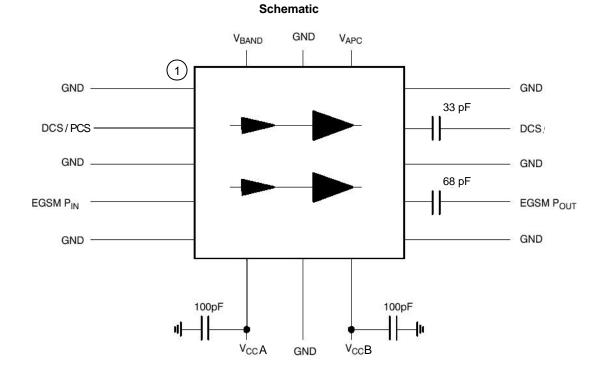
(Unless otherwise specified:  $V_{cc} = 3.2V$ ,  $Z_{IN} = Z_{OUT} = 50\Omega$  System,  $T_{C} = 25$  °C, pulsed operation with 577 $\mu$ sec pulse width and 12.5% duty cycle)

PARAMETER	SYMBOL	MIN	ТҮР	MAX	UNITS
Frequency	fo	880	-	915	MHz
Supply Voltage	V <sub>cc</sub>	2.9	3.2	4.5	V
Control Voltage Range	V <sub>APC</sub>	0.2	2.0	2.7	V
Power Control Current	I <sub>APC</sub>			1	mA
Input Power	P <sub>N</sub>	8	10	12	dBm
Output Power	P <sub>out</sub>		34.5	-	dBm
Power Added Efficiency	PAE	50	55	-	%
Degraded Output Power $V_{cc} = 2.9 V, V_{APC} = 2.4V,$ $P_{N} = 8dBm, T_{c} = 85 °C$		32			dBm
Isolation $V_{APC} = 0.2V, P_{N} = 10 \text{ dBm}$		-25	-35		dBm
Harmonics <sup>(1)</sup> 2 <sup>nd</sup> 3 <sup>rd</sup> 3fo to 12.750 GHz	-	-	-12 -15	-7 -7 -7	dBm dBm dBm
Stability: Load 8:1 VSWR All phase angles	-		-	-70	dBc
Ruggedness: $P_{IN} = 12 \text{ dBm},$ $V_{SUP}=4.5V, V_{APC}=0.2 - 2.8V$				10:1 VSWR All Phases	
Leakage Current V <sub>APC</sub> =0V, V <sub>CC</sub> = 4.5V No input power		-	10	-	μА
Noise Power 925 to 935 MHz 935 to 960 MHz				-72 -84	dBm/100 KHz dBm/100 KHz
Switching Time $V_{APC}$ on to 90% detected $P_{OUT}$				2	µsec
Input VSWR		-	-	2:1	
Output VSWR				2:1	

#### **Electrical Specifications DCS/PCS:**

(Unless otherwise specified:  $V_{cc} = 3.2V$ ,  $Z_{IN} = Z_{OUT} = 50\Omega$  System,  $T_{C} = 25$  °C, pulsed operation with 577 $\mu$ sec pulse width and 12.5% duty cycle)

PARAMETER	SYMBOL	MIN	ТҮР	MAX	UNITS
Frequency DCS	fo	1710	-	1785	MHz
Frequency PCS	fo	1850	-	1910	MHz
Supply Voltage	V <sub>cc</sub>	2.9	3.2	4.5	V
Control Voltage Range	V <sub>APC</sub>	0.2	2.0	2.7	V
Power Control Current	I <sub>APC</sub>			1	mA
Input Power	P <sub>ℕ</sub>	6	8	10	dBm
Output Power DCS	P <sub>OUT</sub>		31.5	-	dBm
Output Power PCS	P <sub>OUT</sub>		TBD	-	dBm
Power Added Efficiency (DCS)	PAE	45	50	-	%
Power Added Efficiency (PCS)	PAE	TBD	TBD	-	%
Degraded Output Power (DCS/PCS) $V_{CC} = 2.9 \text{ V}, V_{APC} = 2.4 \text{ V},$ $P_{\mathbb{N}} = 6 \text{dBm}, T_{C} = 85 ^{\circ}\text{C}$		29.5			dBm
Isolation $V_{APC} = 0.2V, P_{IN} = 10 \text{ dBm}$		-30	-35		dBm
Harmonics <sup>(1)</sup> 2 <sup>nd</sup> 3 <sup>rd</sup> 3fo to 12.750 GHz	:	-	-12 -15	-7 -7 -7	dBm dBm dBm
Stability: Load 8:1 VSWR All phase angles	-		-	-70	dBc
Ruggedness: $P_{\mathbb{N}} = 10 \text{ dBm},$ $V_{SUP}=4.5V, V_{APC}=0.2 - 2.8V$				10:1 VSWR All Phases	
Leakage Current V <sub>APC</sub> =0V, V <sub>CC</sub> = 4.5V No input power		-	10	-	μΑ
Noise Power 20 MHz offset				-76	dBm/100 KHz
Switching Time $V_{_{APC}}$ on to 90% detected $P_{_{OUT}}$				2	μsec
Input VSWR		-	-	2:1	
Output VSWR		-	-	2:1	



Pin	Name	Description	Pin	Name	Description
1	GND	Ground	9	GND	Ground
2	DCS/PCS	DCS/PCS RF Input Signal	10	EGSM P <sub>OUT</sub>	GSM RF output
3	GND	Ground	11	GND	Ground
4	EGSM P <sub>N</sub>	GSM RF Input Signal	12	DCS/PCS	DCS/PCS RF output
5	GND	Ground	13	GND	Ground
6	V <sub>cc</sub> A	Supply Voltage	14	V <sub>APC</sub>	Power Control
7	GND	Ground	15	GND	Ground
8	V <sub>cc</sub> B	Supply Voltage	16	V <sub>BAND</sub> <sup>(1)</sup>	Band Select

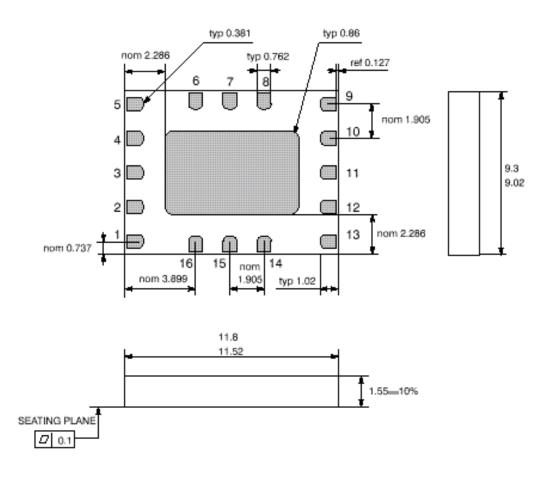
Notes:

1. Vband:

EGSM 0.0 to 0.5V DCS/PCS: 2.0 to 2.8V

### Package Outline Drawing Bottom View

Dimensions in mm.



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